NSN 5962-00-434-3029

Memory Microcircuit - Page 1 of 1



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Body Length:

Between 0.660 inches and 0.785 inches

Body Width:

Between 0.220 inches and 0.280 inches

Body Height:

Between 0.140 inches and 0.180 inches

Maximum Power Dissipation Rating:

800.0 milliwatts

Operating Tempurature Range:

+0.0/+70.0 degrees celsius

Storage Tempurature Range:

-25.0/+125.0 degrees celsius

Features Provided:

Monolithic and negative outputs and positive outputs

Inclosure Material:

Plastic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

Dual 2 input

Case Outline Source And Designator:

T0-116 joint electron device engineering council

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

8.0 volts power source

Time Rating Per Chacteristic:

20.00 nanoseconds propagation delay time, low to high level output and 20.00 nanoseconds propagation delay time, high to low level output

output

Memory Device Type:

Rom

Terminal Type And Quantity:

14 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0